The LTC1540 is an ultralow power, single comparator with built-in reference. The comparator’s features include less than 0.6µA supply current over the commercial temperature range, a 1.182V ±2% reference, programmable hysteresis and TTL/CMOS outputs that sink and source current. The reference output can drive a bypass capacitor of up to 0.01µF without oscillation.

The comparator operates from a single 2V to 11V supply or a dual ±1V to ±5.5V supply. Comparator hysteresis is easily programmed by using two resistors and the HYST pin. Each comparator’s input operates from the negative supply to within 1.3V of the positive supply. The comparator output stage can continuously source up to 40mA. By eliminating the cross-conducting current that normally occur when the comparator changes logic states, power supply glitches are eliminated.

The LTC1540 is available in the 8-pin MSOP and SO packages. For space limited applications, the LTC1540 is available in a 3mm x 3mm low profile (0.8mm) dual fine-pitch leadless package (DFN).
LTC1540

**ABSOLUTE MAXIMUM RATINGS**

Voltage
- \( V^+ \) to \( V^- \), \( V^+ \) to GND, GND to \( V^- \).........12V to −0.3V
- \( I_{IN^+}, I_{IN^-}, HYST \)............... \((V^+ + 0.3V)\) to \((V^- − 0.3V)\)
- \( \text{REF} \)....................... \((V^+ + 0.3V)\) to \((V^- − 0.3V)\)
- \( \text{OUT} \).......................... \((V^+ + 0.3V)\) to \((\text{GND} − 0.3V)\)

Current
- \( I_{IN^+}, I_{IN^-}, HYST \)................................................. 20mA
- \( \text{REF} \)................................................................... 20mA
- \( \text{OUT} \).................................................................. 50mA

OUT Short-Circuit Duration (\( V^+ \leq 5.5V \))...... Continuous

Power Dissipation.............................................................. 500mW

Operating Temperature Range
- LTC1540C.......................................................... 0°C to 70°C
- LTC1540I.......................................................... −40°C to 85°C

Storage Temperature Range ........... −65°C to 150°C

(DD Package) ..................................................... −65°C to 125°C

Lead Temperature (Soldering, 10 sec).........................300°C

**PACKAGE/ORDER INFORMATION**

Consult LTC Marketing for parts specified with wider operating temperature ranges. *Temperature grades are identified by a label on the shipping container.

**ELECTRICAL CHARACTERISTICS**

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at \( T_A = 25°C \). \( V^+ = 5V, V^- = \text{GND} = 0V, T_A = 25°C \) unless otherwise noted.

<table>
<thead>
<tr>
<th>SYMBOL</th>
<th>PARAMETER</th>
<th>CONDITIONS</th>
<th>MIN</th>
<th>TYP</th>
<th>MAX</th>
<th>UNITS</th>
</tr>
</thead>
<tbody>
<tr>
<td>( V^+ )</td>
<td>Supply Voltage Range</td>
<td>●</td>
<td>2.0</td>
<td>11.0</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td>( I_{CC} )</td>
<td>Supply Current ( I_{IN^+} = I_{IN^-} = 80mV, \text{HYST} = \text{REF}, \text{C-Grade} )</td>
<td>●</td>
<td>0.3</td>
<td>0.68</td>
<td>µA</td>
<td></td>
</tr>
<tr>
<td>( I_{IN} )</td>
<td>Input Leakage Current (( I_{IN^+}, I_{IN^-} )) ( I_{IN^+} = I_{IN^-} = 80mV, \text{HYST} = \text{REF}, \text{I-Grade} )</td>
<td>●</td>
<td>0.71</td>
<td></td>
<td>µA</td>
<td></td>
</tr>
<tr>
<td>( V_{OS} )</td>
<td>Comparator Input Offset Voltage ( V_{\text{CM}} = 2.5V )</td>
<td></td>
<td>( \pm 12 )</td>
<td></td>
<td>mV</td>
<td></td>
</tr>
<tr>
<td>( V_{\text{IN}} )</td>
<td>Input Leakage Current (( I_{IN^+}, I_{IN^-} )) ( V_{IN^+} = V_{IN^-} = 2.5V )</td>
<td></td>
<td>( \pm 0.01 )</td>
<td>( \pm 1.0 )</td>
<td>nA</td>
<td></td>
</tr>
<tr>
<td>( V_{CM} )</td>
<td>Comparator Input Common Mode Range ( V^- )</td>
<td>●</td>
<td>( V^- )</td>
<td>( V^+ − 1.3V )</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td>CMRR</td>
<td>Common Mode Rejection Ratio ( V^- ) to ( V^+ − 1.3V )</td>
<td>0.1</td>
<td>1</td>
<td>mV/V</td>
<td></td>
<td></td>
</tr>
<tr>
<td>PSRR</td>
<td>Power Supply Rejection Ratio ( V^+ = 2V ) to ( 11V )</td>
<td>0.1</td>
<td>1</td>
<td>mV/V</td>
<td></td>
<td></td>
</tr>
</tbody>
</table>

Consult LTC Marketing for parts specified with wider operating temperature ranges. *Temperature grades are identified by a label on the shipping container.

LTC1540 CMS8
LTC1540 IMS8

MS8 PACKAGE
8-LEAD PLASTIC MSOP
\( T_{\text{MAX}} = 150°C, \theta_{JA} = 250°C/W \)

DD PACKAGE
8-LEAD (3mm × 3mm) PLASTIC DFN
\( T_{\text{MAX}} = 125°C, \theta_{JA} = 160°C/W \) (NOTE 2) UNDERSIDE METAL CONNECTED TO \( V^- \) (PCB CONNECTION OPTIONAL)

Order Part Number
- LTC1540CDD
- LTC1540IDD
- LTC1540CMS8
- LTC1540IMS8
- LTC1540CS8
- LTC1540IS8
- LTC1540CDD
- LTC1540IDD
- LTC1540CMS8
- LTC1540IMS8
- LTC1540CS8
- LTC1540IS8
- LTCE
- LTADV

Order Part Number
- LTC1540CS8
- LTC1540IS8
- LTC1540CMS8
- LTC1540IMS8
- LTCE
- LTADV

Consult LTC Marketing for parts specified with wider operating temperature ranges. *Temperature grades are identified by a label on the shipping container.
### ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ C$. $V^+ = 5V$, $V^- = GND = 0V$, $T_A = 25^\circ C$ unless otherwise noted.

#### SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS
--- | --- | --- | --- | --- | --- | ---
$V_{HYST}$ | Hysteresis Input Voltage Range | ● REF – 50mV REF | | | | V
$\tau_{PD}$ | Propagation Delay | $C_{OUT} = 100pF$ Overdrive = 10mV Overdrive = 100mV | 60 | 50 | | µs
$V_{OH}$ | Output High Voltage | $I_O = –13mA$ | ● | | | V
$V_{OL}$ | Output Low Voltage | $I_O = 1.8mA$ | ● | | | V

#### Reference

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
--- | --- | --- | --- | --- | --- | ---
$V_{REF}$ | Reference Voltage | No Load (SO-8)/(DFN) Commercial MS8 Commercial (SO-8)/(MS8)/(DFN) Industrial | 1.158 | 1.182 | 1.206 | V
$\Delta V_{REF}$ | Load Regulation | $0 \leq I_{SOURCE} \leq 100\mu A$ | | | | mV
$V^+ = 3V$, $V^- = GND = 0V$, $T_A = 25^\circ C$ unless otherwise noted.

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
--- | --- | --- | --- | --- | --- | ---
$V^+$ | Supply Voltage Range | ● | 2 | 11 | | V
$I_{CC}$ | Supply Current | $I^{IN} = I^{IN} = 80mV$, $HYST = REF$, C-Grade $I^{IN} = I^{IN} = 80mV$, $HYST = REF$, I-Grade | | 0.28 | 0.64 | | µA

#### Comparator

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
--- | --- | --- | --- | --- | --- | ---
$V_{DS}$ | Comparator Input Offset Voltage | $V_{CM} = 2.5V$ LTC1540CMS8/IMS8 | | | | mV
| | | $\pm 12 \pm 15 \pm 16$ | mV
$I_{IN}$ | Input Leakage Current ($I^{IN}^+, I^{IN}^-$) Input Leakage Current (HYST) | $V_{IN}^+ = V_{IN}^- = 1.5V$ | | $\pm 0.01 \pm 0.02$ | | nA
$V_{CMR}$ | Comparator Input Common Mode Range | $V^-$ to $V^+ – 1.3V$ | | 0.1 | 1 | mV/V
$PSRR$ | Power Supply Rejection Ratio | $V^+ = 2V$ to $11V$ | | 0.1 | 1 | mV/V
$V_{HYST}$ | Hysteresis Input Voltage Range | ● REF – 50mV REF | | | | V
$\tau_{PD}$ | Propagation Delay | $C_{OUT} = 100pF$ Overdrive = 10mV Overdrive = 100mV | 70 | 60 | | µs
$V_{OH}$ | Output High Voltage | $I_O = –8mA$ | ● | | | V
$V_{OL}$ | Output Low Voltage | $I_O = 0.8mA$ | ● | | | V

#### Reference

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP | MAX | UNITS |
--- | --- | --- | --- | --- | --- | ---
$V_{REF}$ | Reference Voltage | No Load (SO-8)/(DFN) Commercial MS8 Commercial (SO-8)/(MS8)/(DFN) Industrial | 1.158 | 1.182 | 1.206 | V
$\Delta V_{REF}$ | Load Regulation | $0 \leq I_{SOURCE} \leq 100\mu A$ | | 0.75 | 3.5 | mV
$0 \leq I_{SINK} \leq 10\mu A$ | | 0.5 | 1.5 | mV

**Note 1:** Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

**Note 2:** The $\theta_{JA}$ specified for the DD package is with minimal PCB heat spreading metal. Using expanded metal area on all layers of a board reduces this value.
TYPICAL PERFORMANCE CHARACTERISTICS

Supply Current vs Temperature

Reference Voltage vs Temperature

Reference Voltage Load Regulation (Sink)

Reference Voltage Load Regulation (Source)

Comparator Output Voltage (High) vs Load Current

Comparator Output Voltage (Low) vs Load Current

Comparator Short-Circuit Current vs Supply Voltage

Comparator Response Time vs Input Overdrive

Hysteresis Control
**PIN FUNCTIONS**

**GND (Pin 1):** Ground. Connect to V− for single supply operation.

**V− (Pin 2):** Negative Supply. Potential should be more negative than GND. Connect to ground for single supply operation.

**IN+ (Pin 3):** Noninverting Comparator Input. Input common mode range from V− to V+ – 1.3V. Input current typically 10pA at 25°C.

**IN− (Pin 4):** Inverting Comparator Input. Input common mode range from V− to V+ – 1.3V. Input current typically 10pA at 25°C.

**HYST (Pin 5):** Hysteresis Input. Connect to REF if not used. Input voltage range is from VREF to VREF – 50mV.

**REF (Pin 6):** Reference Output. 1.182V with respect to V−. Can source up to 1mA and sink 10µA at 25°C. Drive 0.01µF bypass capacitor without oscillation.

**V+ (Pin 7):** Positive Supply operating voltage is from 2V to 11V.

**OUT (Pin 8):** Comparator CMOS Output. Swings from GND to V+. Output can source up to 40mA and sink 5mA.

---

**APPLICATIONS INFORMATION**

The LTC1540 is a nanopower comparator with a built-in 1.182V reference. Features include programmable hysteresis, wide supply voltage range (2V to 11V) and the ability of the reference to drive up to a 0.01µF capacitor without oscillation. The comparator’s CMOS outputs can source up to 40mA while supply current glitches that normally occur when switching logic states, have been eliminated.

**Power Supplies**

The comparator operates from a single 2V to 11V supply. The LTC1540 includes a separate ground for the comparator output stage, allowing a split supply ranging from ±1V to ±5.5V. Connecting V− to GND will allow single supply operation. If the comparator output is required to source more than 1mA, or the supply source impedance is high, V+ should be bypassed with a 0.1µF capacitor.

**Comparator Outputs**

The comparator output swings between GND and V+ to assure TTL compatibility with a split supply. The output is capable of sourcing up to 40mA and sinking up to 5mA while still maintaining nanoampere quiescent currents. The output stage does not generate crowbar switching currents during transitions which helps minimize parasitic feedback through the supply pins.

**Voltage Reference**

The internal bandgap reference has a voltage of 1.182V referenced to V−. The reference accuracy is ±2.0% from 0°C to 70°C. It can source up to 1mA and sink up to 10µA with a 5V supply. The reference can drive a bypass capacitor of up to 0.01µF without oscillation and by inserting a series resistor, capacitance values up to 10µF can be used (Figure 1).

Figure 2 shows the resistor value required for different capacitor values to achieve critical damping. Bypassing the reference can help prevent false tripping of the comparators by preventing glitches on V+ or reference load transients from disturbing the reference output voltage.
APPLICATIONS INFORMATION

Figure 1. Damping the Reference Output

Figure 2. Damping Resistance vs Bypass Capacitor Value

Figure 3 shows the bypassed reference output with a square wave applied to the V+ pin. Resistors R2 and R3 set 10mV of hysteresis voltage band while R1 damps the reference response. Note that the comparator output doesn’t trip.

Low Voltage Operation: V+ = 1.6V

The guaranteed minimum operating voltage is 2V (or ±1V). As the total supply voltage is reduced below 2V, the performance degrades and the supply current falls. At low supply voltages, the comparator’s output drive is reduced and the propagation delay increases. The VREF and VOS are also slightly worse. The useful input voltage range extends from the negative supply to 0.9V below the positive supply. Test your prototype over the full temperature and supply voltage range if operation below 2V is anticipated. Because of the increase in supply current, operation below 1.5V is not recommended (Figure 4).

Figure 3a. Power Supply Transient Test Circuit

Figure 3b. Power Supply Transient Rejection

Figure 4. Supply Current vs Supply Voltage
Hysteresis

Hysteresis can be added to the LTC1540 by connecting a resistor (R1) between the REF and HYST pins and a second resistor (R2) from HYST to V− (Figure 5).

The difference between the upper and lower threshold voltages, or hysteresis voltage band (V_{HB}), is equal to twice the voltage difference between the REF and HYST pins.

When more hysteresis is added, the upper threshold increases the same amount as the low threshold decreases. The maximum voltage allowed between REF and HYST pins is 50mV, producing a maximum hysteresis voltage band of 100mV. The hysteresis band may vary by up to 15%. If hysteresis is not wanted, the HYST pin should be shorted to REF. Acceptable values for I_{REF} range from 0.1µA to 5µA. If 2.4M is chosen for R2, then the value of R1 (kΩ) is equal to the value of V_{HB} (mV).

\[ R1 = \frac{V_{REF}}{I_{BIAS}} = \frac{1.182V}{1µA} = 1.18M \]

\[ R2 = \frac{R1}{2} \]

\[ R2 = 1.18M \]

Level Detector

The LTC1540 is ideal for use as a nanopower level detector as shown in Figure 6. R1 and R2 form a voltage divider from V_{IN} to the noninverting comparator input. R3 and R4 set the hysteresis voltage, and R5 and C1 bypass the reference output. The following design procedure can be used to select the component values:

1. Choose the V_{IN} voltage trip level, in this example 4.65V.
2. Calculate the required resistive divider ratio.
   \[ \text{Ratio} = \frac{V_{REF}}{V_{IN}} \]
   \[ \text{Ratio} = \frac{1.182V}{4.65V} = 0.254 \]
3. Choose the required hysteresis voltage band at the input V_{HBIN}, in this example 60mV. Calculate the hysteresis voltage band referred to the comparator input V_{HB}.
   \[ V_{HB} = (V_{HBIN})(\text{Ratio}) \]
   \[ V_{HB} = (60mV)(0.254) \]
   \[ V_{HB} = 15.24mV \]
4. Choose the values for R3 and R4 to set the hysteresis.
   \[ R4 = 2.4M \]
   \[ R3 (kΩ) = 15k, V_{HB} (mV) = 15mV \]
5. Choose the values for R1 and R2 to set the trip point.

\[ R1 = \frac{V_{REF}}{I_{BIAS}} = \frac{1.182V}{1µA} = 1.18M \]

\[ R2 = R1 \]

\[ R2 = 1.18M \]

\[ R2 = 3.40M \]
TYPICAL APPLICATIONS

3.3V Output Low Dropout Linear Regulator

The LTC1540 can be connected as a micropower ($I_Q = 5.5\mu A$ at $V_{IN} = 5V$) low dropout linear regulator (Figure 7). When the output is low, Q1 turns on, allowing current to charge output capacitor C1. Local feedback formed by R4, Q1 and Q2 creates a constant-current source from the 5V input to C1. R4, R1 and Q2's $V_{BE}$ also provide current limiting in the case of an output short-circuit to ground. C2 reduces output ripple, while the R2-R3 feedback voltage divider establishes the output voltage.

Auto Power-Off Source

Figure 8 shows the circuit for a 30mA power supply that has a timed auto power-off function. The comparator output is the switched power supply output. With a 10mA load, it typically provides a voltage of ($V_{BAT} - 0.17V$). The whole circuit draws a mere $0.8\mu A$ of quiescent current with $V_{BAT} = 5V$. The three resistor voltage divider programs 50mV of hysteresis for the comparator, and sets the IN$^-$ voltage at 200mV. This gives an IN$^+$ trip threshold of approximately 150mV.

The RC time constant determines the maximum power-on time of the OUT pin before power down occurs. This period can be approximated by:

$$t = 4.6RC \text{ (seconds)}$$

The actual time will vary with both the leakage current of the capacitor and the input current at the IN$^+$ pin.

Figure 7. 3.3V Output Low Dropout Linear Regulator

Figure 8. Auto Power-Off Switch Operates on 0.8\mu A Quiescent Current
TYPICAL APPLICATIONS

Low-Battery Detect

Figure 9 shows how to use the LTC1540 for a low-battery detect, drawing only 1.4µA at $V_{BAT} = 2V$. The circuit is powered by a 2-cell NiCd battery. The $V_{BAT}$ pin could be as low as 1.6V when the batteries are completely depleted. The electrical specifications of the LTC1540 guarantee operation down to a supply voltage of 2V, but it is still functional with the supply as low as 1.6V. Some parameters, such as $V_{REF}$ and $V_{OS}$, will be degraded on lower supply voltages. The input voltage range extends from 0.9V below the positive supply to the negative supply.

Figure 9. Low-Battery Detect Works Down to 1.6V
DD Package
8-Lead Plastic DFN (3mm × 3mm)
(Reference LTC DWG # 05-08-1698)

MS8 Package
8-Lead Plastic MSOP
(Reference LTC DWG # 05-08-1660)

NOTE:
1. DRAWING TO BE MADE A JEDEC PACKAGE OUTLINE M0-229 VARIATION OF (WEED-1)
2. ALL DIMENSIONS ARE IN MILLIMETERS
3. DIMENSIONS OF EXPOSED PAD ON BOTTOM OF PACKAGE DO NOT INCLUDE MOLD FLASH. MOLD FLASH, IF PRESENT, SHALL NOT EXCEED 0.15mm ON ANY SIDE
4. EXPOSED PAD SHALL BE SOLDER PLATED

NOTE:
1. DIMENSIONS IN MILLIMETER/(INCH)
2. DRAWING NOT TO SCALE
3. DIMENSION DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.152mm (.006") PER SIDE
4. DIMENSION DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSIONS. INTERLEAD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.152mm (.006") PER SIDE
5. LEAD COPLANARITY (BOTTOM OF LEADS AFTER FORMING) SHALL BE 0.102mm (.004") MAX
S8 Package
8-Lead Plastic Small Outline (Narrow .150 Inch)
(Reference LTC DWG # 05-08-1610)

RECOMMENDED SOLDER PAD LAYOUT

NOTE:
1. DIMENSIONS IN INCHES
2. DRAWING NOT TO SCALE
3. THESE DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS.
   MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED .006” (0.15mm)
RF Field Detector

Figure 10 shows the complete circuit for a field detector which was tested at 445MHz. A transmission line is used to match the detector diode (1N5712) to a quarter-wave whip antenna. The 0.23λ wavelength transmission line section transforms the 1pF (350Ω) diode junction capacitance to a virtual short at the base of the antenna. At the same time it converts the received antenna current to a voltage loop at the diode, giving excellent sensitivity.

The rectified output is monitored by the LTC1540 comparator. The internal reference is used to set up a threshold of about 18mV at the inverting input. A rising edge at the comparator output triggers a one shot that temporarily enables answer back and any other pulsed functions.

The total supply current is 400nA. Among other monolithic one shots, the CD4047 draws the least amount of transient current.

![Circuit Diagram](image-url)